NSN 5962-01-346-9913

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View Online at https://aerobasegroup.com/nsn/5962-01-346-9913

Overall Height:

0.425 inches

Overall Width:

Between 0.590 inches and 0.620 inches

Body Length:

1.290 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

0.210 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-55.0/+150.0 degrees celsius

Features Provided:

Burn in and electrostatic sensitive and monolithic and programmable and static operation

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

12 input

Case Outline Source And Designator:

D-3 mil-m-38510

Current Rating Per Characteristic:

85.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, memory digital static ram

Voltage Rating And Type Per Characteristic:

0.3 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

55.00 nanoseconds access

Memory Device Type:

Ram

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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